TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74HC4051AP, TC74HC4051AF, TC74HC4051AFT TC74HC4052AP, TC74HC4052AF, TC74HC4052AFT TC74HC4053AP, TC74HC4053AF, TC74HC4053AFT

#### TC74HC4051AP/AF/AFT

8-Channel Analog

Multiplexer/Demultiplexer

### TC74HC4052AP/AF/AFT

Dual 4-Channel Analog Multiplexer/Demultiplexer

#### TC74HC4053AP/AF/AFT

Triple 2-Channel Analog Multiplexer/Demultiplexer

The TC74HC4051A/4052A/4053A are high speed CMOS ANALOG MULTIPLEXER/DEMULTIPLEXER fabricated with silicon gate C<sup>2</sup>MOS technology. They achieve the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

The TC74HC4051A has an 8 channel configuration, the TC74HC4052A has a 4 channel  $\times$  2 configuration and the TC74HC4053A has a 2 channel  $\times$  3 configuration.

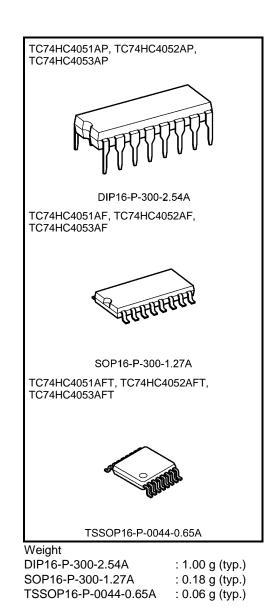
The digital signal to the control terminal turns "ON" the corresponding switch of each channel a large amplitude signal ( $V_{CC} - V_{EE}$ ) can then be switched by the small logical amplitude ( $V_{CC} - GND$ ) control signal.

For example, in the case of  $V_{CC} = 5 V$ , GND = 0 V,  $V_{EE} = -5 V$ , signals between -5 V and +5 V can be switched from the logical circuit with a single power supply of 5 V. As the ON-resistance of each switch is low, they can be connected to circuits with low input impedance.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

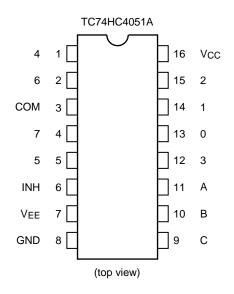
### Features

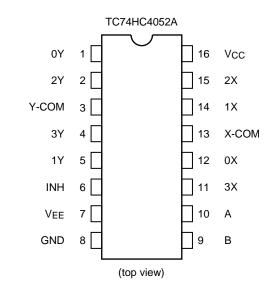
- High speed:  $t_{pd} = 15$  ns (typ.) at VCC = 5 V, VEE = 0 V
- Low power dissipation:  $I_{CC} = 4 \mu A \pmod{at Ta} = 25^{\circ}C$
- High noise immunity: V<sub>NIH</sub> = V<sub>NIL</sub> = 28% V<sub>CC</sub> (min)
- Low ON resistance: RON = 50  $\Omega$  (typ.) at VCC VEE = 9 V
- High noise immunity: THD = 0.02% (typ.) at  $V_{CC} V_{EE} = 9 V$
- Pin and function compatible with 4051/4052/4053B

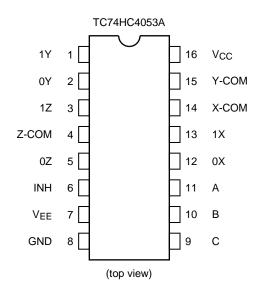


Start of commercial production 1986-05

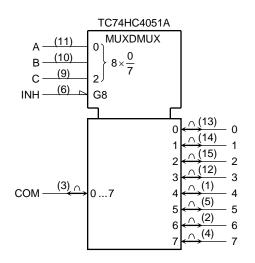
# **Pin Assignment**

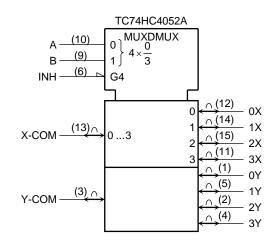


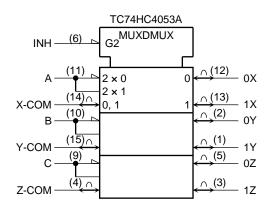




# IEC Logic Symbol







# **Truth Table**

	Contro	I Inputs		"ON" Channel					
Inhibit	C*	В	А	HC4051A	HC4052A	HC4053A			
L	L	L	L	0	0X, 0Y	0X, 0Y, 0Z			
L	L	L	Н	1	1X, 1Y	1X, 0Y, 0Z			
L	L	Н	L	2	2X, 2Y	0X, 1Y, 0Z			
L	L	Н	Н	3	3X, 3Y	1X, 1Y, 0Z			
L	Н	L	L	4	_	0X, 0Y, 1Z			
L	Н	L	н	5	_	1X, 0Y, 1Z			
L	Н	Н	L	6	—	0X, 1Y, 1Z			
L	Н	Н	Н	7	—	1X, 1Y, 1Z			
Н	Х	Х	Х	None	None	None			

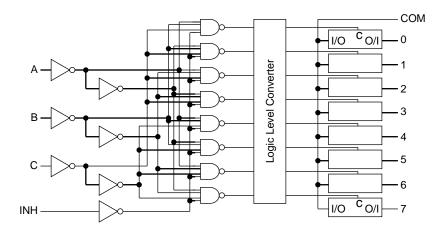
X: Don't care

\*: Except HC4052A

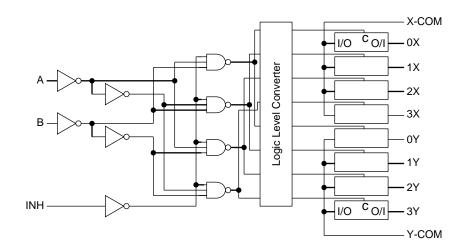


## System Diagram

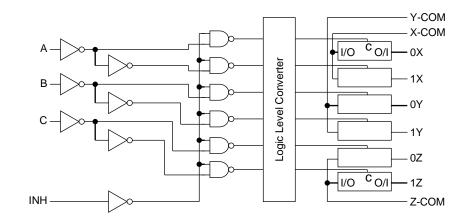
### TC74HC4051A



#### TC74HC4052A



#### TC74HC4053A



### Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	Vcc	-0.5 to 7	V
Supply voltage range	VCC-VEE	-0.5 to 13	V
Control input voltage	VIN	-0.5 to V <sub>CC</sub> + 0.5	V
Switch I/O voltage	VI/O	VEE - 0.5 to VCC + 0.5	V
Control input diode current	Іск	±20	mA
I/O diode current	liok	±20	mA
Switch through current	Ι <sub>Τ</sub>	±25	mA
DC V <sub>CC</sub> or ground current	ICC	±50	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP/TSSOP)	mW
Storage temperature	T <sub>stg</sub>	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C should be applied up to 300 mW.

Characteristics	Symbol	Rating	Unit
Supply voltage range	Vcc	2 to 6	V
Supply voltage range	VEE	-6 to 0	V
Supply voltage range	VCC-VEE	2 to 12	V
Control input voltage	Vin	0 to Vcc	V
Switch I/O voltage	VI/O	VEE to VCC	V
Operating temperature	Topr	-40 to 85	°C
		0 to 1000 (V <sub>CC</sub> = 2.0 V)	
Control input rise and fall time	tr, tf	0 to 500 (V <sub>CC</sub> = 4.5 V)	ns
		0 to 400 (V <sub>CC</sub> = 6.0 V)	

### **Operating Ranges (Note)**

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused control inputs must be tied to either V<sub>CC</sub> or GND.

# **Electrical Characteristics**

#### **DC** Characteristics

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit	
	0,11201		V <sub>EE</sub> (V)	V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	0	
				2.0	1.50	_	_	1.50	_		
High-level control input voltage	VIHC	—		4.5	3.15	—	—	3.15	—	V	
				6.0	4.20	—	—	4.20	—		
				2.0	_	_	0.50	_	0.50		
Low-level control input voltage	VILC	—		4.5	—	—	1.35	—	1.35	V	
5				6.0	—	—	1.80	—	1.80		
		$V_{IN} = V_{ILC} \text{ or } V_{IHC}$	GND	4.5	—	85	180	—	225		
		$V_{I/O} = V_{CC}$ to $V_{EE}$	-4.5	4.5	—	55	120	—	150		
	R <sub>ON</sub>	$I_{I/O} \leq 2 \ mA$	-6.0	6.0	—	50	100	_	125		
ON resistance		V <sub>IN</sub> = V <sub>ILC</sub> or V <sub>IHC</sub> V <sub>I/O</sub> = V <sub>CC</sub> or V <sub>EE</sub>	GND	2.0	—	150	—	—	-	Ω	
			GND	4.5	—	70	150	—	190		
		$I_{I/O} \le 2 \text{ mA}$	-4.5	4.5	—	50	100	—	125		
		10 = 2 110 1	-6.0	6.0	—	45	80	—	100		
Difference of ON	ΔR <sub>ON</sub>	$V_{IN} = V_{ILC} \text{ or } V_{IHC}$	GND	4.5	—	10	30	—	35	Ω	
resistance between switches		$V_{I/O} = V_{CC}$ to $V_{EE}$	-4.5	4.5	—	5	12	—	15		
Switches		$I_{I/O} \leq 2 \ mA$	-6.0	6.0	—	5	10	_	12		
Input/output leakage	IOFF	$V_{OS} = V_{CC} \text{ or } GND$	GND	6.0	_	_	±60	_	±600		
current		$V_{IS} = GND \text{ or } V_{CC}$	-6.0	6.0	_	_	±100	_	±1000	nA	
(switch off)		$V_{IN} = V_{ILC} \text{ or } V_{IHC}$	0.0	0.0			1.00		21000		
Switch input leakage current		$V_{OS} = V_{CC}$ or GND	GND	6.0	_	_	±60	_	±600	_	
(switch on, output open)	IIZ	$V_{IN} = V_{ILC} \text{ or } V_{IHC}$	-6.0	6.0	—	—	±100	—	±1000	nA	
Control input current	l <sub>IN</sub>	$V_{IN} = V_{CC} \text{ or } GND$	GND	6.0	_	_	±0.1	_	±1.0	μA	
			GND	6.0	_	_	4.0	_	40.0	μΑ	
Quiescent supply current	lcc	$V_{IN} = V_{CC} \text{ or } GND$	-6.0	6.0	_	—	8.0	—	80.0		

### AC Characteristics (CL = 50 pF, input: tr = tf = 6 ns, GND = 0 V)

Characteristics	Symbol		Test Condition			-	Ta = 25°0	C	Ta = -40 to 85°C		Unit
Unaracteriolico				V <sub>EE</sub> (V)	V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Unit
				GND	2.0	_	25	60	_	75	
Phase difference				GND	4.5	_	6	12	_	15	
between input and output	φι/Ο	All types		GND	6.0	_	5	10	_	13	ns
				-4.5	4.5		4	_	_	_	
				GND	2.0	_	64	225	_	280	
				GND	4.5	_	18	45	_	56	
		4051A	(Note 1)	GND	6.0	_	15	38	_	48	
				-4.5	4.5		18	_	_	_	
				GND	2.0	_	64	225	_	280	
	t <sub>pZL</sub>			GND	4.5	_	18	45	_	56	
Output enable time	tpZH	4052A	(Note 1)	GND	6.0	_	15	38	_	48	ns
	-			-4.5	4.5		18	_	_	_	
				GND	2.0	_	50	225	_	280	
			(Note 1)	GND	4.5	_	14	45	_	56	
		4053A		GND	6.0	_	12	38	_	48	
				-4.5	4.5		14	_	_	_	
	tpLZ tpHZ		(Note 1)	GND	2.0	_	100	250	_	315	
				GND	4.5	_	33	50	_	63	ns
		4051A		GND	6.0	_	28	43	_	54	
				-4.5	4.5		29	_	_	_	
		4052A	(Note 1)	GND	2.0	-	100	250	_	315	
				GND	4.5	_	33	50	_	63	
Output disable time				GND	6.0	_	28	43	_	54	
				-4.5	4.5		29	_	_	_	
				GND	2.0	_	95	225	_	280	
			(Note 1)	GND	4.5	_	30	45	_	56	
		4053A		GND	6.0	_	26	38	_	48	
				-4.5	4.5		26	_	_	_	
Control input capacitance	CIN	All types		_	_		5	10	_	10	pF
		4051A				_	36	70	_	70	
COMMON terminal capacitance	CIS	4052A		-5.0	5.0	_	19	40	_	40	pF
capacitance		4053A				_	11	20	_	20	
		4051A					7	15	_	15	
SWITCH terminal	Cos	4052A		-5.0	5.0	_	7	15	_	15	pF
capacitance		4053A				_	7	15	_	15	
		4051A				_	0.95	2	_	2	
Feedthrough	Cios	4052A		-5.0	5.0	_	0.85	2	_	2	pF
capacitance		4053A				_	0.75	2	_	2	
		4051A	(Note 2)			_	70	_	_	_	
Power dissipation	Cpd	4052A	(Note 2)	GND	5.0	_	71	_	_	_	pF
capacitance		4053A	(Note 2)			_	67	_	_	_	

Note 1:  $RL = 1 k\Omega$ 

Note 2: CPD is defined as the value of the internal equivalent capacitance of IC which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $ICC (opr) = CPD \cdot VCC \cdot fIN + ICC$ 

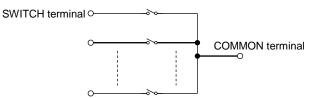
### Analog Switch Characteristics (GND = 0 V, Ta = 25°C) (Note 1)

		Test C		Тур.	Unit		
Characteristics	Symbol						
		$R_L = 10 \ k\Omega$ ,	$V_{IN} = 4.0 V_{p-p}$	-2.25	2.25	0.025	
Sine wave distortion (T.H.D)		C <sub>L</sub> = 50 pF	$V_{IN} = 8.0 V_{p-p}$	-4.5	4.5	0.020	%
· · ·		f <sub>IN</sub> = 1 kHz	VIN = 11.0 Vp-p	-6.0	6.0	0.018	
			All (Note 2)			120	
			4051A (Note 3)	-2.25	2.25	45	
			4052A (Note 3)	-2.25	2.20	70	
		A divet for one line of a shirts in	4053A (Note 3)			95	
		Adjust f <sub>IN</sub> voltage to obtain 0dBm at V <sub>OS</sub>	All (Note 2)	-4.5	4.5	190	MHz
Frequency response	4	Increase $f_{IN}$ frequency until dB meter reads -3dB R <sub>L</sub> = 50 $\Omega$ , C <sub>L</sub> = 10 pF $f_{IN}$ = 1 MHz, sine wave	4051A (Note 3)			70	
(switch on)	fmax		4052A (Note 3)			110	
			4053A (Note 3)			150	
			All (Note 2)		6.0	200	
			4051A (Note 3)	-6.0		85	
			4052A (Note 3)			140	
			4053A (Note 3)			190	
		V <sub>IN</sub> is centered at (V <sub>CC</sub> - V <sub>EE</sub>	)/2	-2.25	2.25	-50	
Feed through attenuation (switch off)		Adjust input for 0dBm		-4.5	4.5	-50	dB
(ownon on)		$R_L = 600 \Omega$ , $C_L = 50 pF$ $f_{IN} = 1 MHz$ , sine wave	-6.0	6.0	-50		
				-2.25	2.25	60	
Crosstalk		$R_L$ = 600 $\Omega$ , $C_L$ = 50 pF		-4.5	4.5	140	mV
(control input to signal output)		f <sub>IN</sub> = 1 MHz, square wave (	$(t_r = t_f = 6 ns)$	-6.0	6.0	200	
		Adjust V <sub>IN</sub> to obtain 0dBm at	input	-2.25	2.25	-50	
Crosstalk (between any switches)		$R_L = 600 \Omega, C_L = 50 pF$					
(between any switches)		f <sub>IN</sub> = 1 MHz, sine wave		-6.0	6.0	-50	

Note 1: These characteristics are determined by design of devices.

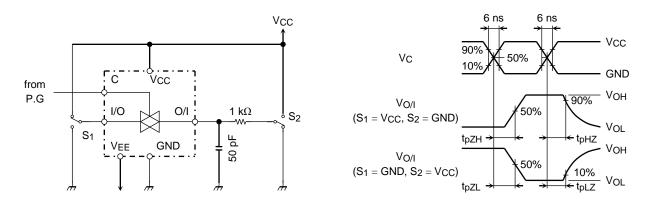
Note 2: Input COMMON terminal, and measured at SWITCH terminal.

Note 3: Input SWITCH terminal, and measured at COMMON terminal.

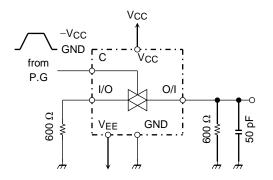


### **Switching Characteristics Test Circuits**

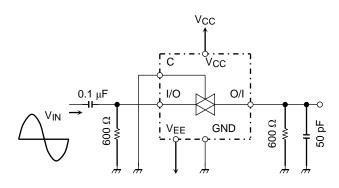
1. tpLZ, tpHZ, tpZL, tpZH



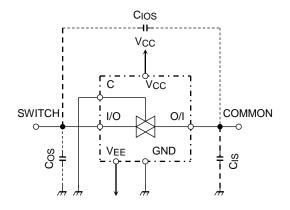
2. Cross Talk (control input-switch output) fIN = 1 MHz duty = 50% tr = tf = 6 ns



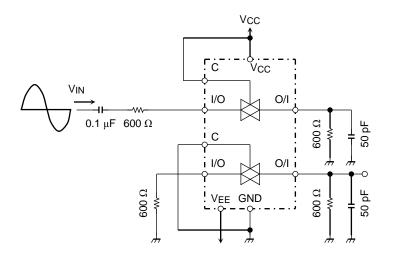
### 3. Feedthrough Attenuation



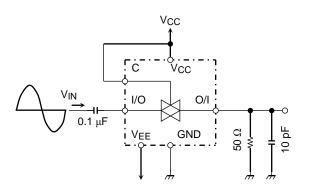
### 4. Clos, Cls, Cos



### 5. Cross Talk (between any two switches)



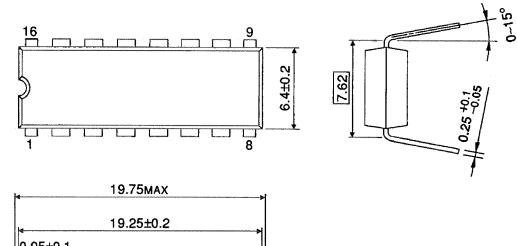
### 6. Frequency Response (switch on)

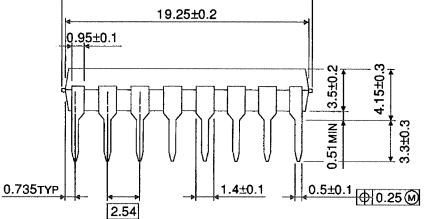


### **Package Dimensions**

DIP16-P-300-2.54A

Unit : mm





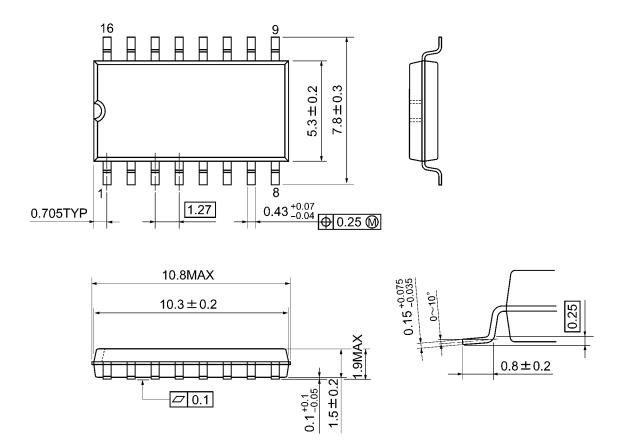
Weight: 1.00 g (typ.)



### **Package Dimensions**

SOP16-P-300-1.27A

Unit: mm

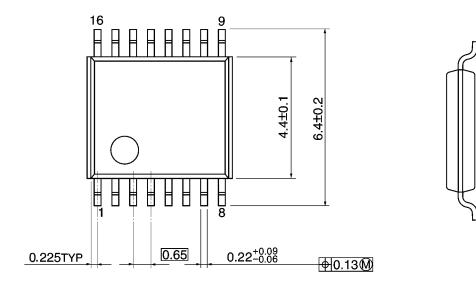


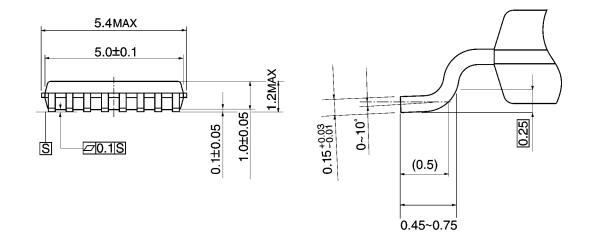
Weight: 0.18 g (typ.)

# **Package Dimensions**

TSSOP16-P-0044-0.65A

Unit: mm





Weight: 0.06 g (typ.)

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